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- **EPIC™** (Enhanced-Performance Implanted **CMOS) Submicron Process**
- Typical V<sub>OLP</sub> (Output Ground Bounce)  $< 0.8 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) > 2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Inputs Accept Voltages to 5.5 V
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per **JESD 17**
- **Package Options Include Plastic** Small-Outline (D), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW) Packages, Ceramic Flat (W), Chip Carriers (FK), and DIPs (J)

#### description

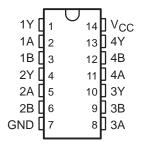
The SN54LVC02A quadruple 2-input positive-NOR gate is designed for 2.7-V to 3.6-V V<sub>CC</sub> operation and the SN74LVC02A quadruple 2-input positive-NOR gate is designed for 1.65-V to 3.6-V V<sub>CC</sub> operation.

The 'LVC02A devices perform the Boolean function  $Y = \overline{A + B}$  or  $Y = \overline{A} \bullet \overline{B}$  in positive logic.

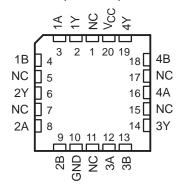
Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

The SN54LVC02A is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74LVC02A is characterized for operation from -40°C to 85°C.

#### SN54LVC02A . . . J OR W PACKAGE SN74LVC02A . . . D. DB. OR PW PACKAGE (TOP VIEW)



#### SN54LVC02A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

#### **FUNCTION TABLE** (each gate)

INP	UTS	OUTPUT
Α	В	Y
Н	Χ	L
Х	Н	L
L	L	Н



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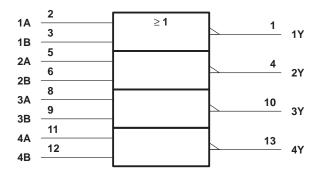
EPIC is a trademark of Texas Instruments Incorporated



## SN54LVC02A, SN74LVC02A QUADRUPLE 2-INPUT POSITIVE-NOR GATES

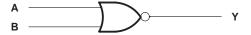
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### logic symbol<sup>†</sup>



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, J, PW, and W packages.

#### logic diagram, each gate (positive logic)



### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply-voltage range, V <sub>CC</sub>	
Input-voltage range, V <sub>I</sub> (see Note 1)	
Output-voltage range, VO (see Notes 1 and 2)	0.5 V to V <sub>CC</sub> + 0.5 V
Input clamp current, $I_{IK}$ ( $V_I < 0$ )	–50 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	–50 mA
Continuous output current, IO	±50 mA
Continuous current through V <sub>CC</sub> or GND	±100 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 3): D package	27°C/W
DB package	ge 158°C/W
PW packa	ge 170°C/W
Storage temperature range, T <sub>stq</sub>	

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. The value of V<sub>CC</sub> is provided in the recommended operating conditions table.
- 3. The package thermal impedance is calculated in accordance with JESD 51.



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## recommended operating conditions (see Note 4)

			SN54L	VC02A	SN74L	VC02A	UNIT	
			MIN	MAX	MIN	MAX	I UNII	
Vac	Supply voltage	Operating	2	3.6	1.65	3.6	V	
Vcc	Supply voltage	Data retention only	1.5		1.5		]	
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$			0.65 × V <sub>CC</sub>			
ViH	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$			1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		2			
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$				0.35 × V <sub>CC</sub>		
$V_{IL}$	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$				0.7	V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		0.8		
٧ <sub>I</sub>	Input voltage		0	5.5	0	5.5	V	
٧o	Output voltage		0	Vcc	0	Vcс	V	
		V <sub>CC</sub> = 1.65 V				-4	mA	
la	High lovel output outropt	V <sub>CC</sub> = 2.3 V				-8		
ЮН	High-level output current	V <sub>CC</sub> = 2.7 V		-12		-12		
		V <sub>CC</sub> = 3 V		-24		-24		
		V <sub>CC</sub> = 1.65 V				4		
	Low lovel output ourrent	V <sub>CC</sub> = 2.3 V				8	A	
lOL	Low-level output current	V <sub>CC</sub> = 2.7 V		12		12	mA	
		V <sub>CC</sub> = 3 V		24		24	1	
T <sub>A</sub>	Operating free-air temperature	-	-55	125	-40	85	°C	

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	·	SN	54LVC0	2A	SN	74LVC02	2A	UNIT
PARAMETER	TEST CONDITIONS	vcc	MIN	TYP†	MAX	MIN	TYP	MAX	UNII
	I <sub>OH</sub> = -100 μA	1.65 V to 3.6 V				V <sub>CC</sub> -0	.2		
		2.7 V to 3.6 V	VCC-0	.2					
	$I_{OH} = -4 \text{ mA}$	1.65 V				1.2			
Voн	$I_{OH} = -8 \text{ mA}$	2.3 V				1.7			V
	10 m 4	2.7 V	2.2			2.2			
	I <sub>OH</sub> = -12 mA 3 V 2.4		2.4						
	I <sub>OH</sub> = -24 mA	3 V	2.2			2.2			
	Jan - 100 uA	1.65 V to 3.6 V						0.2	
	I <sub>OL</sub> = 100 μA	2.7 V to 3.6 V			0.2				
V	I <sub>OL</sub> = 4 mA	1.65 V						0.45	V
VOL	I <sub>OL</sub> = 8 mA	2.3 V						0.7	ľ
	I <sub>OL</sub> = 12 mA	2.7 V			0.4			0.4	
	I <sub>OL</sub> = 24 mA	3 V			0.55			0.55	
lį	V <sub>I</sub> = 5.5 V or GND	3.6 V			±5			±5	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V			10			10	μΑ
ΔlCC	One input at V <sub>CC</sub> – 0.6 V, Other inputs at V <sub>CC</sub> or GND	2.7 V to 3.6 V		·	500			500	μΑ
C <sub>i</sub>	$V_I = V_{CC}$ or GND	3.3 V		5			5		pF

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

## switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 2.7 V		$V_{CC} = 2.7 \text{ V}$ $V_{CC} = 3.3 \text{ V}$ $\pm 0.3 \text{ V}$		3.3 V 3 V	UNIT
			MIN	MAX	MIN	MAX		
<sup>t</sup> pd	A or B	Y		5.4	1	4.4	ns	

# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

		FROM (INPUT)	TO (OUTPUT)	SN74LVC02A							
	PARAMETER			V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
				TYP	MIN	MAX	MIN	MAX	MIN	MAX	
I	<sup>t</sup> pd	A or B	Y	13.4	1	7.4		5.4	1	4.4	ns
	t <sub>sk(o)</sub> ‡									1	ns

<sup>‡</sup> Skew between any two outputs of the same package switching in the same direction

## operating characteristics, T<sub>A</sub> = 25°C

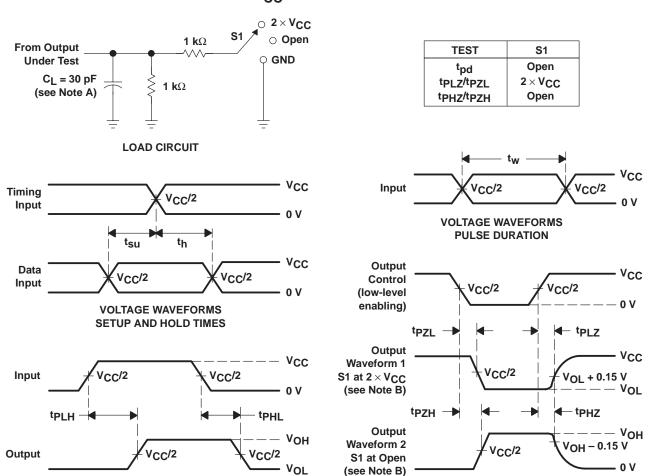
PARAMETER		TEST	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	UNIT
		CONDITIONS	TYP	TYP	TYP	ONT
C <sub>pd</sub>	Power dissipation capacitance per gate	f = 10 MHz	7.5	8.5	9.5	pF



**VOLTAGE WAVEFORMS** 

**ENABLE AND DISABLE TIMES** 

## PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50~\Omega$ ,  $t_f \leq$  2 ns.  $t_f \leq$  2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLZ and tpHZ are the same as tdis.

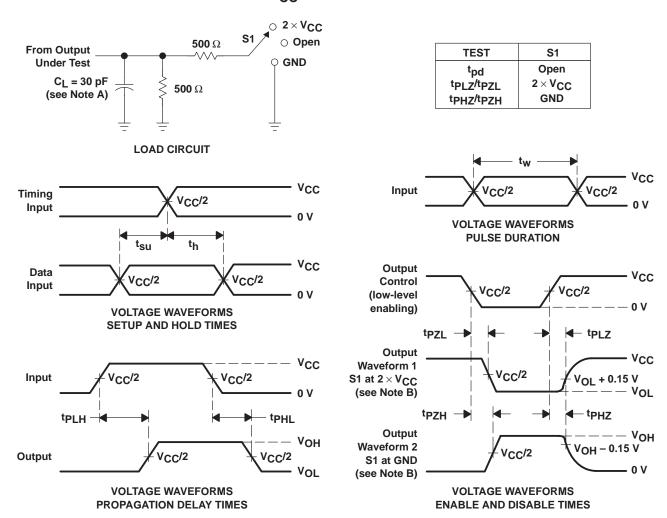
**VOLTAGE WAVEFORMS** 

**PROPAGATION DELAY TIMES** 

- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

# PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



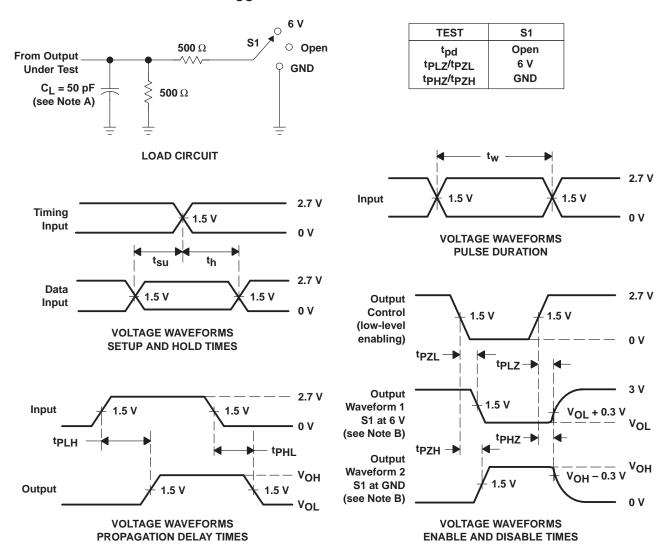
NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_Q = 50 \Omega$ ,  $t_f \leq 2$  ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzl and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



# PARAMETER MEASUREMENT INFORMATION $V_{CC}$ = 2.7 V AND 3.3 V $\pm$ 0.3 V



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_Q = 50 \ \Omega$ ,  $t_f \leq$  2.5 ns.  $t_f \leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpl 7 and tpH7 are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms

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